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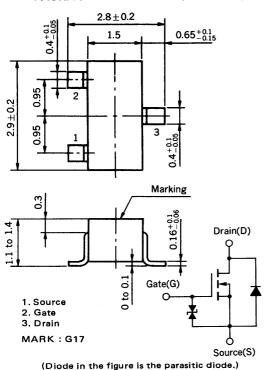
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MOS FIELD EFFECT TRANSISTOR **2SK1589**

N-CHANNEL MOS FET FOR SWITCHING

PACKAGE DIMENSIONS (Unit: mm)



The 2SK1589, N-channel vertical type MOS FET, is a switching device which can be driven directly by the output of ICs having a 5 V power source.

As the MOS FET has low on-state resistance and excellent switching characteristics, it is suitable for driving actuators such as motors, relays, and solenoids.

FEATURES

- Directly by ICs having a 5 V power source.
- Not necessary to consider driving current because of its high input impedance.

QUALITY GRADE

Standard

Please refer to "Quality grade on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

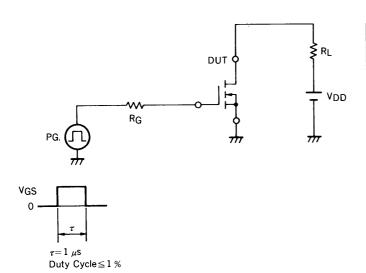
ABSOLUTE MAXIMUM RATINGS (Ta = 25 °C)

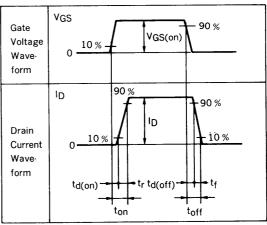
PARAMETER	SYMBOL	RATINGS	UNIT	TEST CONDITIONS
Drain to Source Voltage	V _{DSS}	100	V	V _{GS} = 0
Gate to Source Voltage	V _{GSS}	±20	V	V _{DS} = 0
Drain Current	I _{D(DC)}	±100	mA	
Drain Current	I _{D(pulse)}	±200	mA	PW \leq 10 ms, Duty Cycle \leq 50 %
Total Power Dissipation	PT	200	mW	
Channel Temperature	T _{ch}	150	°C	
Storage Temperature	T _{stg}	-55 to +150	°C	

ELECTRICAL CHARACTERISTICS (T_a = 25 °C)

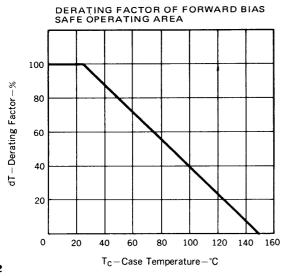
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain Cut-off Current	IDSS			1.0	μΑ	V _{DS} = 100 V, V _{GS} = 0
Gate Leakage Current	I _{GSS}			±1.0	μΑ	V _{GS} = ±20 V, V _{DS} = 0
Gate Cut-off Voltage	VGS(off)	0.8	1.5	1.8	V	$V_{DS} = 5.0 \text{ V}, I_{D} = 1.0 \mu\text{A}$
Forward Transfer Admittance	ly _{fs} l	20	38		mS	$V_{DS} = 5.0 \text{ V}, I_D = 10 \text{ mA}$
Drain to Source On-State Resistance	R _{DS} (on)1		19	30	Ω	V _{GS} = 4.0 V, I _D = 10 mA
Drain to Source On-State Resistance	R _{DS(on)2}		15	25	Ω	V _{GS} = 10 V, I _D = 10 mA
Input Capacitance	C _{iss}		16		pF	V _{DS} = 5.0 V, V _{GS} = 0, f = 1 MHz
Output Capacitance	Coss		12		pF	
Feedback Capacitance	C _{rss}		3		рF	
Turn-On Delay Time	^t d(on)		17		ns	V_{DD} = 5.0 V, I_{D} = 10 mA $V_{GS(on)}$ = 5.0 V, R_{G} = 10 Ω R_{L} = 500 Ω
Rise Time	t _r		10		ns	
Turn-Off Delay Time	td(off)		68		ns	
Fall Time	tf		38		ns	

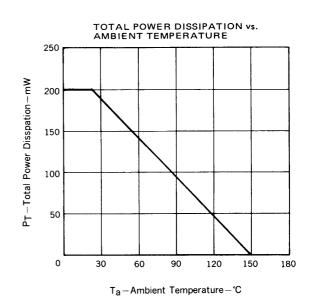
SWITCHING TIME MEASUREMENT CIRCUIT AND CONDITIONS



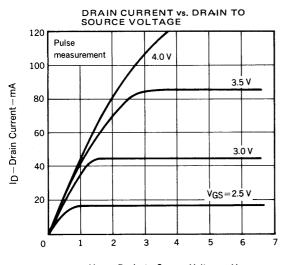


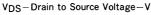
TYPICAL CHARACTERISTICS (T_a = 25 °C)

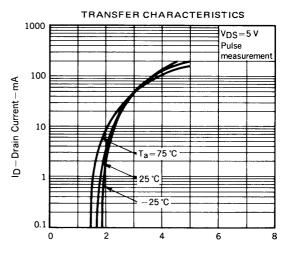




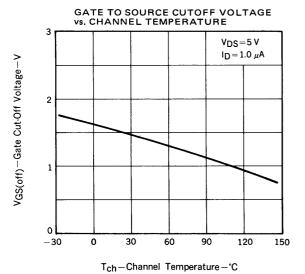
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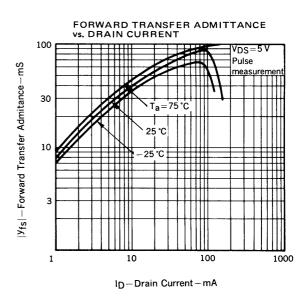


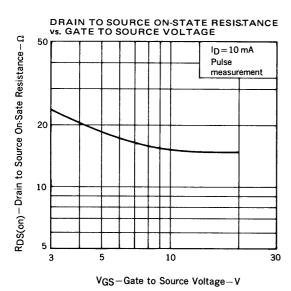


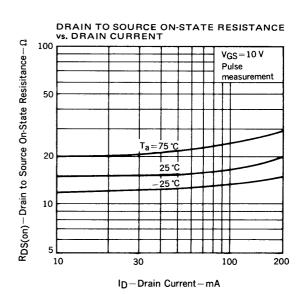


VGS-Gate to Source Voltage-V

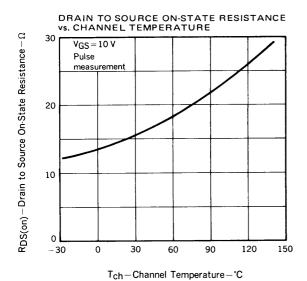


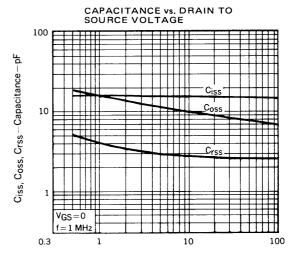




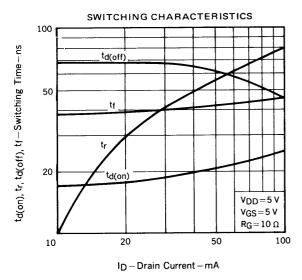


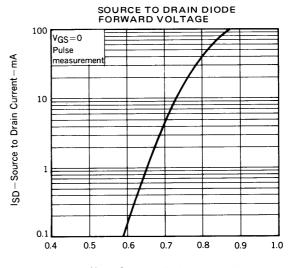






VDS-Drain to Source Voltage-V





RECOMMENDED SOLDERING CONDITIONS

Mounting of this product by soldering should be done under the following conditions.

Please consult our representatives about soldering methods and conditions other than these.

SURFACE MOUNT TYPE

For details of the recommended soldering conditions, see the information document "SMT MANUAL" (IEI-1207).

Soldering Method	Soldering Conditions	Symbol for Recommended Conditions	
Infrared Reflow	Package peak temp.: 230 °C Soldering time: within 30 sec (above 210 °C) Soldering times: 1, Days limitation: none*	IR30-00	
Vapor Phase Soldering	Package peak temp.: 215 °C Soldering time: within 40 sec (above 200 °C) Soldering times: 1, Days limitation: none*	VP15-00	
Wave Soldering	Soldering bath temp.: below 260 °C Soldering time: within 10 sec Soldering times: 1, Days limitation: none*	WS60-00	

^{*:} Stored days under storage conditions at 25 °C and below 65 % R.H. after the dry-pack has been opened.

Note 1 Combination of soldering methods should be avoided.

[MEMO]

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The devices listed in this document are not suitable for use in the field where very high reliability is required including, but not limited to, aerospace equipment, submarine cables, unclear reactor control systems and life support systems. If customers intend to use NEC devices for above applications or those inted to use "Standard", or "Special" quality grade NEC devices for the applications not intended by NEC, please contact our sales people in advance.

Application examples recommended by NEC Corporation

Standard: Data processing and office equipment, Communication equipment (terminal, mobile). Test and

Measurement equipment, Audio and Video equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Communication equipment (trunk line), Train and

Traffic control devices, industrial robots, Burning control systems, antidisaster systems, anticrime

systems etc.